



CHUANGYUAN TECHNOLOGES (HK) LIMITED

SOD-323 Plastic-Encapsulate Diode

1SS357 Schottky Diodes

FEATURES

- Small Package
- Low VF, low IR

MAKING: S31



Maximum Ratings and Electrical Characteristics, Single Diode @ $T_A=25^\circ C$

Parameter	Symbol	Limits		Unit
Peak reverse voltage	V_{RM}	45		V
DC reverse voltage	V_R	40		V
Mean rectifying current	I_o	0.1		A
Peak forward surge current	I_{FSM}	1		A
Junction temperature	T_j	125		$^\circ C$
Storage temperature	T_{stg}	-55~+125		$^\circ C$

Electrical Ratings @ $T_A=25^\circ C$

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_F		0.28 0.36	0.6	V	$I_F=1mA$ $I_F=10mA$ $I_F=100mA$
Reverse current	I_R			5	μA	$V_R=40V$
Capacitance between terminals	C_T			25	pF	$V_R=0, f=1MHz$

Typical Characteristics

ISS357

